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April 2001

FDC6310P

SEMICONDUCTOR

Dual P-Channel 2.5V Specified PowerTrench[®] MOSFET

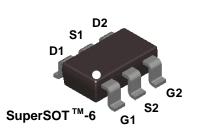
General Description

These P-Channel 2.5V specified MOSFETs are produced using Fairchild Semiconductor's advanced PowerTrench process that has been especially tailored to minimize on-state resistance and yet maintain low gate charge for superior switching performance.

These devices have been designed to offer exceptional power dissipation in a very small footprint for applications where the bigger more expensive SO-8 and TSSOP-8 packages are impractical.

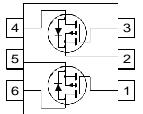
Applications

- Load switch
- Battery protection
- Power management



Features

- -2.2 A, -20 V. $R_{DS(ON)}$ = 125 m Ω @ V_{GS} = -4.5 V $R_{DS(ON)}$ = 190 m Ω @ V_{GS} = -2.5 V
- Low gate charge
- Fast switching speed
- + High performance trench technology for extremely low $R_{\text{DS}(\text{ON})}$
- SuperSOT TM -6 package: small footprint 72% smaller than standard SO-8); low profile (1mm thick)



Absolute Maximum Ratings T_{A=25°C} unless otherwise noted

Symbol	Parameter			Ratings	Units	
V _{DSS}	Drain-Source Voltage			-20	V	
V _{GSS}	Gate-Source Voltage			±12	V	
b	Drain Curre	nt – Continuous	(Note 1a)	-2.2	А	
		– Pulsed		-6		
PD	Power Diss	pation for Single Operation	ON (Note 1a)	0.96	W	
			(Note 1b)	0.9		
			(Note 1c)	0.7		
T_J, T_{STG}	Operating and Storage Junction Temperature Range		perature Range	-55 to +150	°C	
Therma	I Charact	eristics				
$R_{\theta JA}$	Thermal Re	ermal Resistance, Junction-to-Ambient (Note 1a)		130	°C/W	
R _{0JC}	Thermal Resistance, Junction-to-Case		Se (Note 1)	60	°C/W	
Packag	e Marking	g and Ordering	Information			
Device Marking		Device	Reel Size	Tape width	Quantity	
.310		FDC6310P	7"	8mm	3000 units	

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FDC6310P

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Char	acteristics		1	1		
BV _{DSS}	Drain–Source Breakdown Voltage	$V_{GS} = 0 V, I_D = -250 \mu A$	-20			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = -250 \ \mu\text{A}$, Referenced to 25°C		-11		mV/°C
DSS	Zero Gate Voltage Drain Current	$V_{DS} = -16 V$, $V_{GS} = 0 V$			-1	μΑ
GSSF	Gate-Body Leakage, Forward	$V_{GS} = 12 \text{ V}, V_{DS} = 0 \text{ V}$			100	nA
GSSR	Gate-Body Leakage, Reverse	$V_{GS} = -12 V$, $V_{DS} = 0 V$			-100	nA
On Char	acteristics (Note 2)			•	•	
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = -250 \ \mu A$	-0.6	-1.0	-1.5	V
<u>ΔVgs(th)</u> ΔTj	Gate Threshold Voltage Temperature Coefficient	$I_D = -250 \ \mu\text{A}$, Referenced to 25°C		3		mV/°0
R _{DS(on)}	Static Drain–Source On–Resistance	$ \begin{array}{l} V_{GS} = -4.5 \ V, b = -2.2 \ A \\ V_{GS} = -2.5 \ V, b = -1.8 \ A \\ V_{GS} = -4.5 \ V, \ b = -2.2 \ A, \ T_J = 125^\circ C \end{array} $		100 145 137	125 190 184	mΩ
D(on)	On–State Drain Current	$V_{GS} = -4.5 V$, $V_{DS} = -5 V$	-6			Α
g _{FS}	Forward Transconductance	$V_{DS} = -5 V$, $I_{D} = -3.5 A$		6		S
Dynamic	Characteristics	•				
Ciss	Input Capacitance	$V_{DS} = -10 V$, $V_{GS} = 0 V$,		337		pF
Coss	Output Capacitance	f = 1.0 MHz		88		pF
Crss	Reverse Transfer Capacitance			51		pF
Switchin	g Characteristics (Note 2)				•	
t _{d(on)}	Turn–On Delay Time	$V_{DD} = -10 V$, $I_D = -1 A$,		9	18	ns
tr	Turn–On Rise Time	$V_{GS} = -4.5 \text{ V}, R_{GEN} = 6 \Omega$		12	22	ns
t _{d(off)}	Turn–Off Delay Time			10	20	ns
t _f	Turn–Off Fall Time			5	10	ns
Qg	Total Gate Charge	$V_{DS} = -10 V$, $I_D = -2.2 A$,		3.7	5.2	nC
Q _{gs}	Gate-Source Charge	$V_{GS} = -4.5 V$		0.65		nC
Q _{gd}	Gate–Drain Charge			1.3		nC
Drain-Se	ource Diode Characteristics	and Maximum Ratings				
s	Maximum Continuous Drain-Source				-0.8	A
V _{SD}	Drain–Source Diode Forward Voltage	$V_{GS} = 0 V$, $I_S = -0.8 A$ (Note 2)	1	0.77	-1.2	V

 R_{6UA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{6UC} is guaranteed by design while R_{6CA} is determined by the user's board design.

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a) 130 °C/W when mounted on a 0.125 in² pad of 2 oz. copper. b) 140°/W when mounted on a .004 in² pad of 2 oz copper

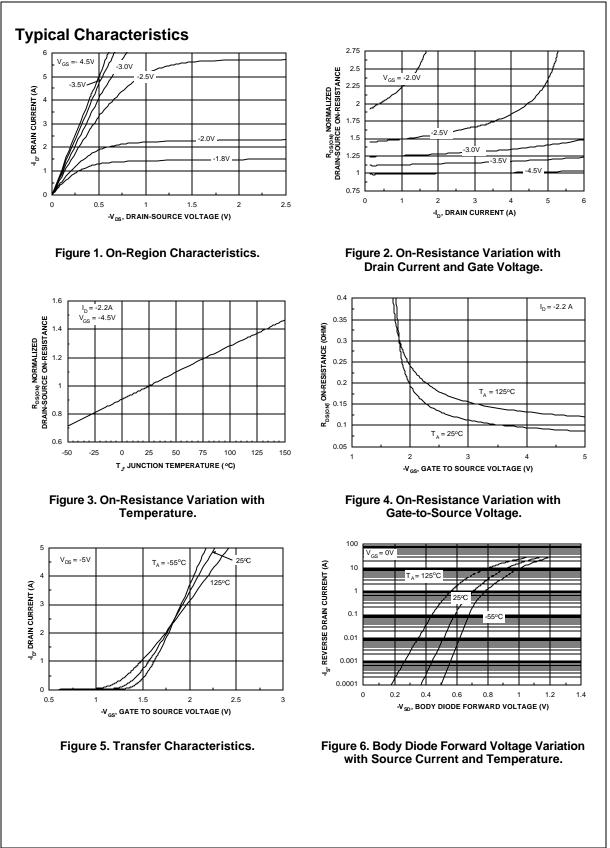


c) 180°/W when mounted on a minimum pad.

Scale 1 : 1 on letter size paper

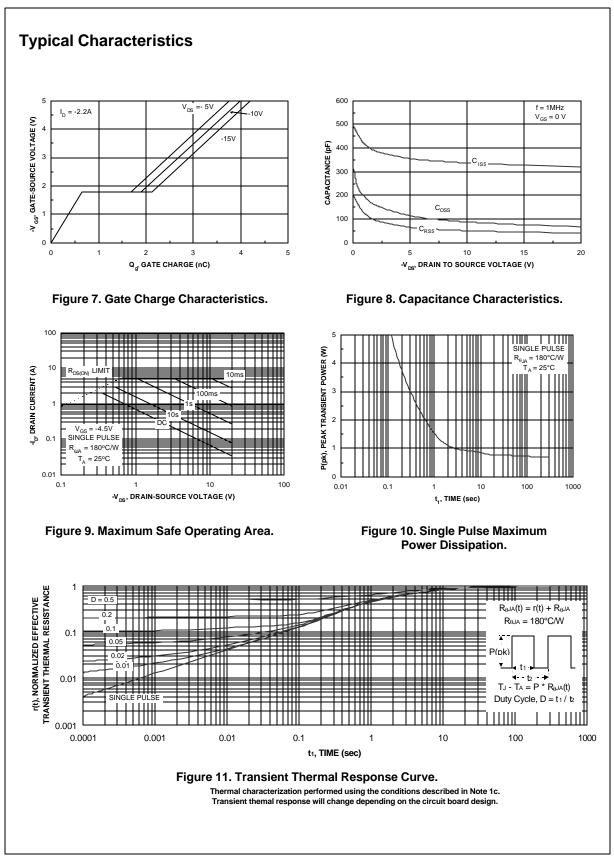
2. Pulse Test: Pulse Width < 300 μ s, Duty Cycle < 2.0%

FDC6310P Rev C(W)



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